L, S-band High Power SPDT Switch



Features

Control voltage :

$$VC(H) = 1.8 \text{ to } 5.3 \text{ V } (3.0 \text{V TYP.})$$

VC(L) = -0.2 to 0.2 V (0V TYP.)

• Low Insertion Loss:

$$L_{ins1} = 0.30 \text{ dB TYP.} @ f = 0.5 \text{ to } 2.0 \text{ GHz}$$

 $L_{ins2} = 0.35 \text{ dB TYP.} @ f = 2.0 \text{ to } 2.5 \text{ GHz}$

 $L_{ins3} = 0.40 \text{ dB TYP.} @ f = 2.5 \text{ to } 3.8 \text{ GHz}$

 L_{ins4} = 0.45 dB TYP. @ f = 3.8 to 6.0 GHz

• High Isolation:

ISL1= 32 dB TYP. @ f = 0.5 to 2.0 GHz

ISL2= 32 dB TYP. @ f = 2.0 to 2.5 GHz

ISL3= 32 dB TYP. @ f = 2.5 to 3.8 GHz

ISL4= 26 dB TYP. @ f = 3.8 to 6.0 GHz

Handling power :

 $P_{in(0.5dB)} = +34 \text{ dBm TYP}.$

@ VC(H) = 3.0 V, VC(L) = 0 V

Applications

Dual-band wireless LAN etc.
 (IEEE 802.11 a/b/g/n/ac)

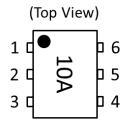
Package

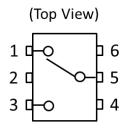
 6-pin lead-less mini mold package (1.5mm x 1.1mm x 0.55mm)

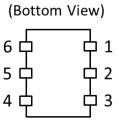
Description

 The CKRF6415MM66 is a pHEMT GaAs MMIC high power SPDT (Single Pole Double Throw) switch which was developed for dual-band wireless LAN.

Pin Configuration And Internal Block Diagram







| Pin No. | Pin Name |
|---------|----------|
| 1 | RF1 |
| 2 | GND |
| 3 | RF2 |
| 4 | VC2 |
| 5 | RFC |
| 6 | VC1 |

Ordering Information

| Part Number | Order Number | Package | Marking | Supplying Form |
|-----------------|-----------------|-------------------|---------|--------------------------------|
| CKRF6415MM66-C2 | CKRF6415MM66-C2 | ·6-pin lead-less | 10A | •Embossed tape 8 mm wide |
| | | mini mold package | | ∙Pin 1, 6 face the perforation |
| | | (Pb-Free) | | side of the tape |
| | | | | ·Qty 9 kpcs/reel |

L, S-band High Power SPDT Switch



Absolute Maximum Ratings

(T_A=+25℃, unless otherwise specified)

| Parameter | Symbol | Rating | Unit |
|-------------------------------|------------------|-------------------------|---------------|
| Control Voltage | VC | 6.0 ^{Note 1} | V |
| Input Power | P _{in} | +34.5 ^{Note 2} | dBm |
| Operating Ambient Temperature | T _A | -45~+85 | ${\mathbb C}$ |
| Storage Temperature | T _{stg} | -55~+150 | $^{\circ}$ |

Note 1. |VC1 - VC2|≤6.0V

2. 3.0V≦|VC1 - VC2|≦5.0V

Recommended Operating Range

 $(T_A=+25^{\circ}C, \text{ unless otherwise specified})$

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
|----------------------------|--------|------|------|------|------|
| Operating Frequency | f | 0.5 | - | 6.0 | GHz |
| Switch Control Voltage (H) | VC(H) | +1.8 | +3.0 | +5.3 | V |
| Switch Control Voltage (L) | VC(L) | -0.2 | 0 | +0.2 | V |

Truth Table

| VC1 | VC2 | RFC-RF1 | RFC-RF2 |
|------|------|---------|---------|
| High | Low | ON | OFF |
| Low | High | OFF | ON |

L, S-band High Power SPDT Switch



Electrical Characteristics 1

 $(T_A=+25^{\circ}C, VC(H)=3.0V, VC(L)=0V, Zo=50\Omega, DC Block Capacitance=8pF, unless otherwise specified)$

| Parameter | Symbol | Condition | MIN. | TYP. | MAX. | Unit |
|------------------------------------|------------------------|--------------------------------------|------|------|------|------|
| Insertion Loss | L _{INS1} | f=0.5 to 2.0GHz Note 1 | | 0.30 | 0.50 | dB |
| | L _{INS2} | f=2.0 to 2.5GHz | | 0.35 | 0.55 | dB |
| | L _{INS3} | f=2.5 to 3.8GHz | | 0.40 | 0.60 | dB |
| | L _{INS4} | f=3.8 to 6.0GHz | | 0.45 | 0.70 | dB |
| Isolation | ISL1 | f=0.5 to 2.0GHz Note 1 | 29 | 32 | | dB |
| | ISL2 | f=2.0 to 2.5GHz | 29 | 32 | | dB |
| | ISL3 | f=2.5 to 3.8GHz | 29 | 32 | | dB |
| | ISL4 | f=3.8 to 6.0GHz | 23 | 26 | | dB |
| Return Loss | RL1 | f=0.5 to 2.0GHz Note 1 | 15 | 20 | | dB |
| | RL2 | f=2.0 to 2.5GHz | 15 | 20 | | dB |
| | RL3 | f=2.5 to 6.0GHz | 10 | 15 | | dB |
| 0.1dB Loss Compression | P _{in(0.1dB)} | f=0.5 to 2.0GHz Note 1 | | +32 | | dBm |
| Input Power Note 2 | | f=2.0 to 6.0GHz | | +31 | | dBm |
| | | f=0.5 to 6.0GHz Note 1 VC(H)=5.0V | | +35 | | dBm |
| 0.5dB Loss Compression | P _{in(0.5dB)} | f=0.5 to 2.0GHz Note 1 | | +34 | | dBm |
| Input Power Note 3 | | f=2.0 to 6.0GHz | | +34 | | dBm |
| 3rd Order Input Intercept Point | IIP ₃ | f=2.5GHz, 2-tone 1MHz Spacing | | 60 | | dBm |
| 2nd Harmonics | 2f0 | f=2.5GHz, P _{in} =+20dBm | | -90 | | dBc |
| | _ | f=6.0GHz, P _{in} =+20dBm | | -90 | | dBc |
| 3rd Harmonics | 3f0 | f=2.5GHz, P _{in} =+20dBm | | -90 | | dBc |
| | | f=6.0GHz, P _{in} =+20dBm | | -90 | | dBc |

Note 1. DC block capacitance = 56pF at f=0.5 to 2.0GHz

Note 3. $P_{in(0.5dB)}$ is the measured input power level when the insertion loss increases 0.5dB more than that of the linear range.

Note 2. $P_{in(0.1dB)}$ is the measured input power level when the insertion loss increases 0.1dB more than that of the linear range.

L, S-band High Power SPDT Switch



Electrical Characteristics 2

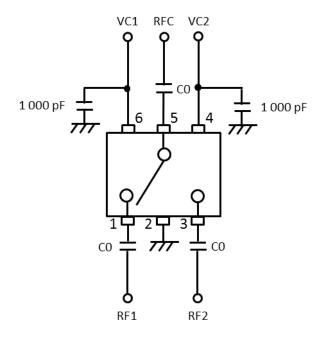
 $(T_A=+25^{\circ}C, VC(H)=3.0V, VC(L)=0V, Zo=50\Omega, DC Block Capacitance=8pF, unless otherwise specified)$

| Parameter | Symbol | Condition | MIN. | TYP. | MAX. | Unit |
|------------------------|---------------------|--|------|------|------|------|
| Error Vector Magnitude | or Vector Magnitude | 802.11a, 64QAM, 54Mbps,Pin≦+25dBm | | 0.5 | | % |
| EVM | EVM | 802.11g, 64QAM, 54Mbps,Pin≦+25dBm | | 0.5 | | % |
| | | 802.11ac, 256QAM, MCS9, 80MHz, Pin≤+25dBm | | 0.5 | | % |
| Switch Control Current | I_{CONT} | RF none | 1 | 2 | 10 | uA |
| Switching Speed | T_SW | 50% CTL to 90/10% RF | | 100 | 250 | ns |

L, S-band High Power SPDT Switch



Evaluation Circuit

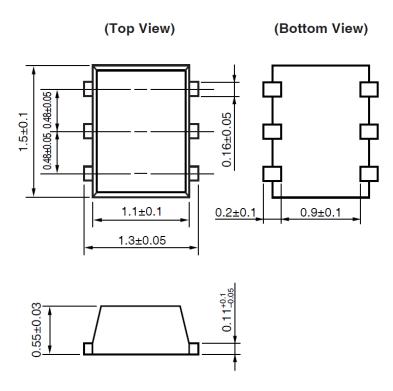


Note C0: 0.5 to 2.0 GHz 56pF : 2.0 to 6.0 GHz 8pF

The application circuits and their parameters are for reference only and are not intended for use in actual design-ins. This device is used it is necessary to use DC Block Capacitance.

Package Dimensions

6-PIN LEAD-LESS MINIMOLD (1511 PKG) (UNIT:mm)



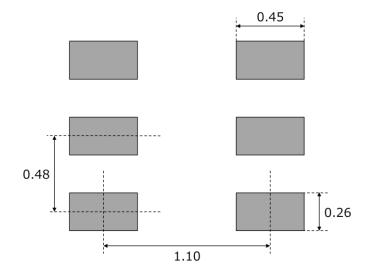
CDS-0022-05 Date Published Oct. 2017 Page 5 of 8

L, S-band High Power SPDT Switch



PCB Layout Footprint

6-PIN LEAD-LESS MINIMOLD (1511 PKG) (UNIT:mm)



The PCB Layout Footprint in this document is for reference only.

L, S-band High Power SPDT Switch



[CAUTION]

- All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice.
- You should not alter, modify, copy, or otherwise misappropriate any CDK product, whether in whole or in part.
- CDK does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third
 parties by or arising from the use of CDK products or technical information described in this document. No license,
 express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights
 of CDK or others.
- Descriptions of circuits, software and other related information in this document are provided only to illustrate the
 operation of semiconductor products and application examples. You are fully responsible for the incorporation of
 these circuits, software, and information in the design of your equipment. CDK assumes no responsibility for any
 losses incurred by you or third parties arising from the use of these circuits, software, or information.
- CDK has used reasonable care in preparing the information included in this document, but CDK does not warrant that such information is error free. CDK assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- Although CDK endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions.
 Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a CDK product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures
 Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final
 - Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the fina products or system manufactured by you.
- Please use CDK products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive.
 CDK assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and
- This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of CDK.
- Please contact a CDK if you have any questions regarding the information contained in this document or CDK products, or if you have any other inquiries.

regulations.

L, S-band High Power SPDT Switch



[Caution in the gallium arsenide (GaAs) product handling]

This product uses gallium arsenide (GaAs) of the toxic substance appointed in laws and ordinances. GaAs vapor and powder are hazardous to human health if inhaled or ingested.

- Do not dispose in fire or break up this product.
- Do not chemically make gas or powder with this product.
- When discard this product, please obey the law of your country.
- Do not lick the product or in any way allow it to enter the mouth.

[CAUTION]

Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions should be used at all times.

CHUO DENSHI KOGYO Co., Ltd.

3400 Kooyama, Matsubase, Uki-City,

Kumamoto 869-0512, Japan Tel: +81-964-32-2730

Fax : +81-964-32-3549

URL: http://www.en.cdk.co.jp/

Contact info for inquiries

Electronic Devices Division Sales and Planning Department

TEL : +81-964-32-2750 E-mail : info@cdk.co.jp FAX : +81-964-32-3549